

J.C. PATENTS
4 VENTURE, SUITE 250
IRVINE, CALIFORNIA 92618
TEL.: (949) 660-0761
FAX: (949) 660-0809
E-MAIL: jcpi@email.msn.com

CERTIFICATE OF TRANSMISSION

February 20, 2003

Atty Docket No.:	JCLA7289
Appl. No.:	09/990,397
Filing Date:	November, 20, 2001
Pages:	Cover + 8

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BY FACSIMILE ONLY

Fax No.: 703-872-9319
Attention: Examiner LEWIS, MONICA
Group Unit: 2822
From: Jiawei Huang, Reg. No. 43,330

FEB 20 2003

TECHNOLOGY CENTER 2800

MESSAGE: Enclosed is an Amendment including amended drawing of Fig. 1 in 8 pages.

Sir:

I hereby certify that this correspondence is being facsimile transmitted to the Patent and Trademark Office on February 20, 2003 at the above indicated fax number.

Sign by: 
Michelle Chang

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Application No.: 09/990,397
Docket No.: JCLA7289

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Examiner: Lewis, Monica

Group Art Unit: 2822

In re PATENT APPLICATION of

Applicants : Jung-Yu Hsieh)

Serial No. : 09/990,397)

Filed : November 20, 2001)

For : Flash Memory Structure)

) Attorney Docket: JCLA7289

AMENDMENT AFTER FINAL OFFICE ACTION

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Assistant Commissioner for Patents
Washington, D.C. 20231

FEB 20 2003

TECHNOLOGY CENTER 2800

Dear Sir:

The Office Action mailed December 19, 2002 (Paper No. 5), has been carefully considered. In response thereto, please enter the following amendments and consider the following remarks.

Amendment

IN THE SPECIFICATION

Please replace the title of invention on page 1 with the following new title:
--FLASH MEMORY STRUCTURE WITH HIGH DIELECTRIC CONSTANT LAYER--

On page 2, line 21, please delete the heading: [SUMMARY OF THE INVENTION].

IN THE DRAWINGS

Please amend Fig. 1 as shown in the attached sheet, a marked copy of which is also enclosed herewith to show the changes made.